**DO-41** 



## 1.0A GLASS PASSIVATED FAST RECOVERY DIODE

### **Features**

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

## **Mechanical Data**

Case: DO-41, Molded Plastic

Terminals: Plated Leads Solderable per

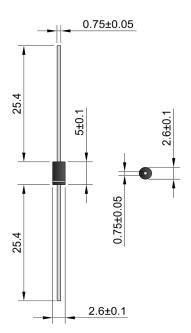
MIL-STD-202, Method 208

Polarity: Cathode Band

Weight: 0.35 grams (approx.)

Mounting Position: AnyMarking: Type Number

Lead Free: For RoHS / Lead Free Version



# Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic  | Symbol             | 1N4933G     | 1N4934G | 1N4935G | 1N4936G | 1N4937G | Unit |
|---|--------------------|-------------|---------|---------|---------|---------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                                | Vrrm<br>Vrwm<br>Vr | 50          | 100     | 200     | 400     | 600     | ٧    |
| RMS Reverse Voltage   | VR(RMS)            | 35          | 70      | 140     | 280     | 420     | V    |
| Average Rectified Output Current (Note 1) @T <sub>A</sub> = 75°C  | lo                 | 1.0         |         |         |         |         | Α    |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single Half Sine-Wave Superimposed on<br>Rated Load (JEDEC Method) | İFSM               | 30          |         |         |         |         | А    |
| Forward Voltage @I <sub>F</sub> = 1.0A  | VFM                | 1.2         |         |         |         |         | V    |
|   | IRM                | 5.0<br>100  |         |         |         |         | μΑ   |
| Reverse Recovery Time (Note 2)  | t <sub>rr</sub>    | 200         |         |         |         |         | nS   |
| Typical Junction Capacitance (Note 3)   | Cı                 | 15          |         |         |         |         | pF   |
| Typical Thermal Resistance Junction to Ambient (Note 1) Typical Thermal Resistance Junction to Lead (Note 1)          | R JA<br>R JL       | 55<br>25    |         |         |         |         | °C/W |
| Operating and Storage Temperature Range   | ТЈ, Тѕтс           | -65 to +150 |         |         |         |         | °C   |

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

- 2. Measured with  $I_F$  = 0.5A,  $I_R$  = 1.0A,  $I_{RR}$  = 0.25A.
- 3. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.



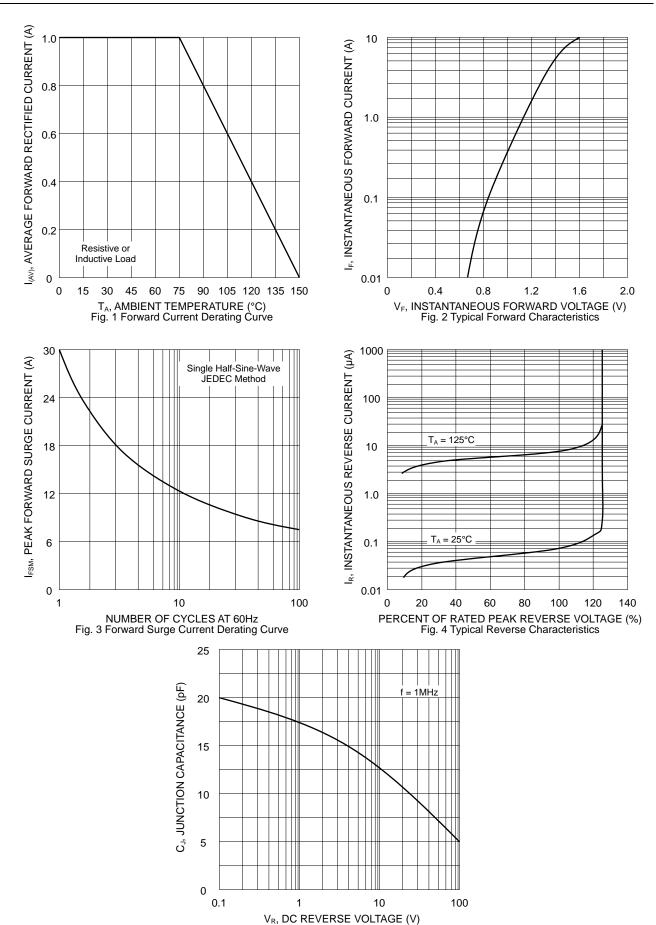
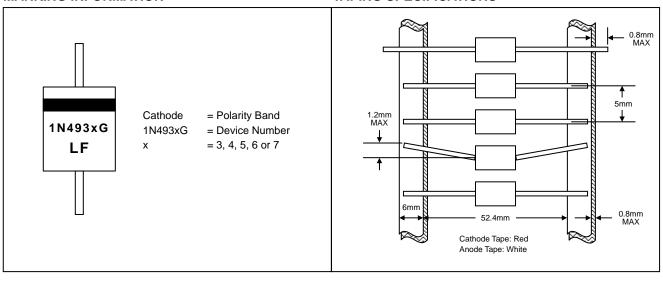


Fig. 5 Typical Junction Capacitance



## **MARKING INFORMATION**

### **TAPING SPECIFICATIONS**



### **PACKAGING INFORMATION**

